MSKSEMI 美森科
SEMICONDUCTOR

ESD   TVS   TSS   MOV   GDT   PLED

L298N(MS)
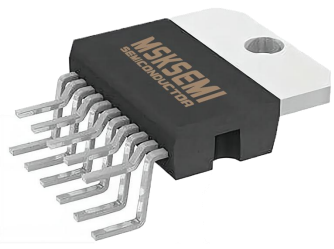
Product specification

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DESCRIPTION

L298N(MS) is a high voltage, high current dual full-bridge driver designed to accept standard

TTL logic levels and drive inductive loads such as relays, solenoids, DC and stepping motors.

CHARACTERISTIC

- OPERATING SUPPLY VOLTAGE UP TO 45V

- TOTAL DC CURRENT UP TO 4 A

- LOW SATURATION VOLTAGE

- LOGICAL "0" INPUT VOLTAGE UP TO 1.5 V

- THE LOGIC POWER SUPPLY AND DRIVE POWER SUPPLY ARE INDEPENDENT OF EACH OTHER
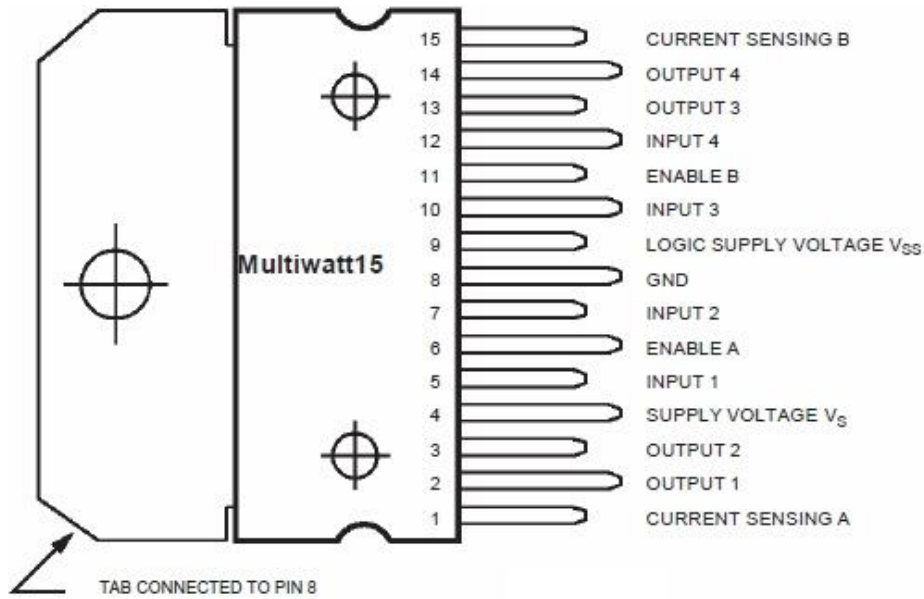
Reference News

PACKAGE OUTLINE	Marking
ZIP-15	MSKSEMI L298N MS****

ordering information

P/N	PKG	QTY
L298N(MS)	ZIP-15	25/One tube 1000/a box of

PIN DEFINITION AND FUNCTION

TAB CONNECTED TO PIN 8

MW.15	Name	Function
1;15	Sense A; Sense B	Between this pin and ground is connected the sense resistor to control the current of the load.
2;3	Out 1; Out 2	Outputs of the Bridge A; the current that flows through the load connected between these two pins is monitored at pin 1.
4	V_S	Supply Voltage for the Power Output Stages. A non-inductive 100nF capacitor must be connected between this pin and ground.
5;7	Input 1; Input 2	TTL Compatible Inputs of the Bridge A.
6;11	Enable A; Enable B	TTL Compatible Enable Input: the L state disables the bridge A (enable A) and/or the bridge B (enable B).
8	GND	Ground.
9	VSS	Supply Voltage for the Logic Blocks. A100nF capacitor must be connected between this pin and ground.
10; 12	Input 3; Input 4	TTL Compatible Inputs of the Bridge B.
13; 14	Out 3; Out 4	Outputs of the Bridge B. The current that flows through the load connected between these two pins is monitored at pin 15.
–	N.C.	Not Connected

PINS AND DEFINITIONS OF L298N(MS)

BLOCK DIAGRAM
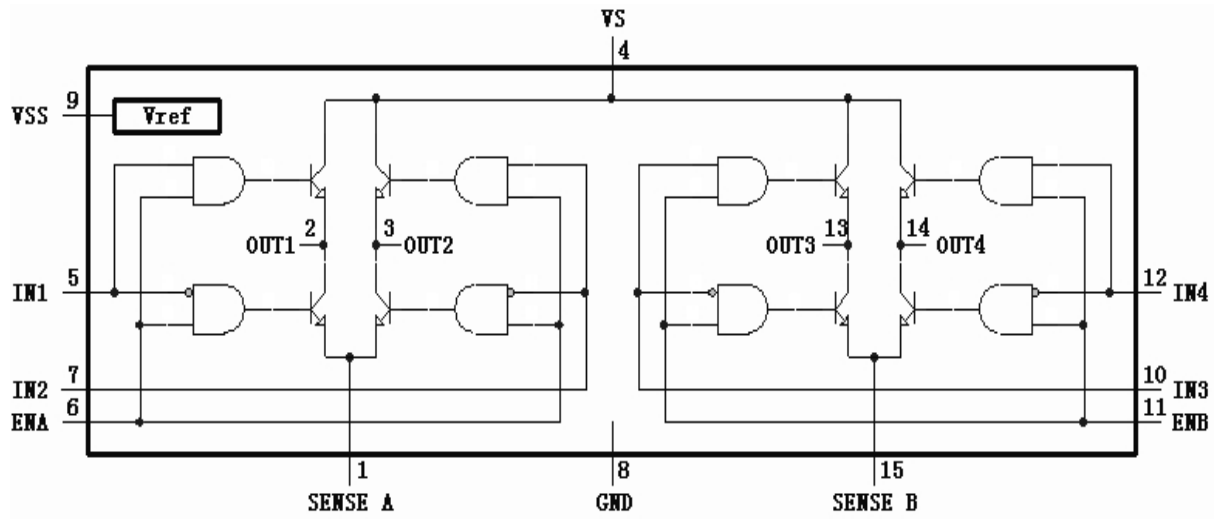
BLOCK DIAGRAM OF L298N-MS

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Conditions			Min.	Typ.	Max.	Unit
V_S	Supply Voltage (pin 4)	Operative Condition			V_{IH} +2.5		46	V
V_{SS}	Logic Supply Voltage (pin 9)				4.5	5	7	V
I_S	Quiescent Supply Current (pin 4)	V_{en} = H; I_L = 0		V_i = L		13	22	mA
				V_i = H		50	70	mA
		V_{en} = L		V_i = X			4	mA
I_{SS}	Quiescent Current from V_{SS} (pin 9)	V_{en} = H; I_L = 0		V_i = L		24	36	mA
				V_i = H		7	12	mA
		V_{en} = L		V_i = X			6	mA
V_{iL}	Input Low Voltage (pins 5, 7, 10, 12)				−0.3		1.5	V
V_{iH}	Input High Voltage (pins 5, 7, 10, 12)				2.3		VSS	V
I_{iL}	Low Voltage Input Current (pins 5, 7, 10, 12)	V_i = L					−10	μA
I_{iH}	High Voltage Input Current (pins 5, 7, 10, 12)	Vi = H ≤ V_{SS} −0.6V				30	100	μA
V_{en} = L	Enable Low Voltage (pins 6, 11)				−0.3		1.5	V
V_{en} = H	Enable High Voltage (pins 6, 11)				2.3		V_{SS}	V
I_{en} = L	Low Voltage Enable Current (pins 6, 11)	V_{en} = L					−10	μA
I_{en} = H	High Voltage Enable Current (pins 6, 11)	V_{en} = H ≤ V_{SS} −0.6V				30	100	μA
$V_{CEsat(H)}$	Source Saturation Voltage	I_L = 1A			0.95	1.35	1.7	V
		I_L = 2A				2	2.7	V
$V_{CEsat(L)}$	Sink Saturation Voltage	I_L = 1A			0.85	1.2	1.6	V
		I_L = 2A				1.7	2.3	V
V_{CEsat}	Total Drop	I_L = 1A			1.80		3.2	V
		I_L = 2A					4.9	V
V_{sens}	Sensing Voltage (pins 1, 15)				−1		2	V

APPLICATION

POWER OUTPUT STAGE

The L298N(MS) integrates two power output stages (A ; B).The power output stage is a bridge configuration and its outputs can drive an inductive load in common or differenzial mode, depending on the state of the inputs. The current that flows through the load comes out from the bridge at the sense output : an external resistor (RSA ; RSB.) allows to detect the intensity of this current.

INPUT STAGE

All the inputs are TTL compatible

POWER

A non inductive capacitor, usually of 100 nF, must be foreseen between both Vs and Vss, to ground, as near as possible to GND pin.The en terminal shall be in L state before the output protection is turned off and on.

OUTPUT PROTECTION

The fast diode shall be selected as the output protection when driving inductive load. When I = 2 A, VF $\leqslant$ 1.2V, TRR $\leqslant$ 200 ns.

PARALLEL CONNECTION

When the driving current is greater than 2A, two groups can be connected in parallel for current expansion.

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DIMENSION

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			5			0.197
B			2.65			0.104
C			1.6			0.063
D		1			0.039	
E	0.49		0.55	0.019		0.022
F	0.66		0.75	0.026		0.030
G	1.02	1.27	1.52	0.040	0.050	0.060
G1	17.53	17.78	18.03	0.690	0.700	0.710
H1	19.6			0.772		
H2			20.2			0.795
L	21.9	22.2	22.5	0.862	0.874	0.886
L1	21.7	22.1	22.5	0.854	0.870	0.886
L2	17.65		18.1	0.695		0.713
L3	17.25	17.5	17.75	0.679	0.689	0.699
L4	10.3	10.7	10.9	0.406	0.421	0.429
L7	2.65		2.9	0.104		0.114
M	4.25	4.55	4.85	0.167	0.179	0.191
M1	4.63	5.08	5.53	0.182	0.200	0.218
S	1.9		2.6	0.075		0.102
S1	1.9		2.6	0.075		0.102
Dia1	3.65		3.85	0.144		0.152

外观及尺寸
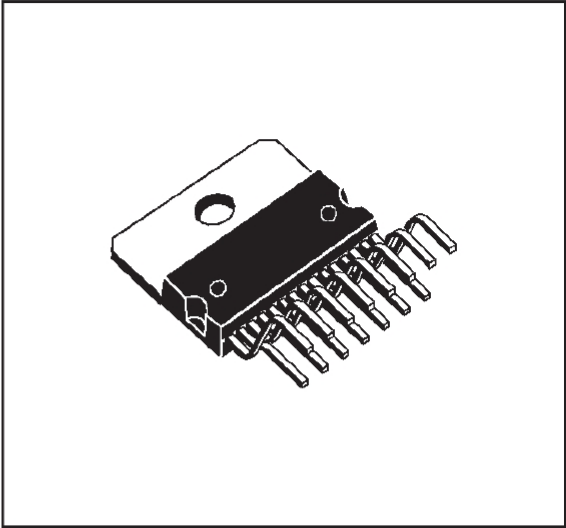
Multiwatt15
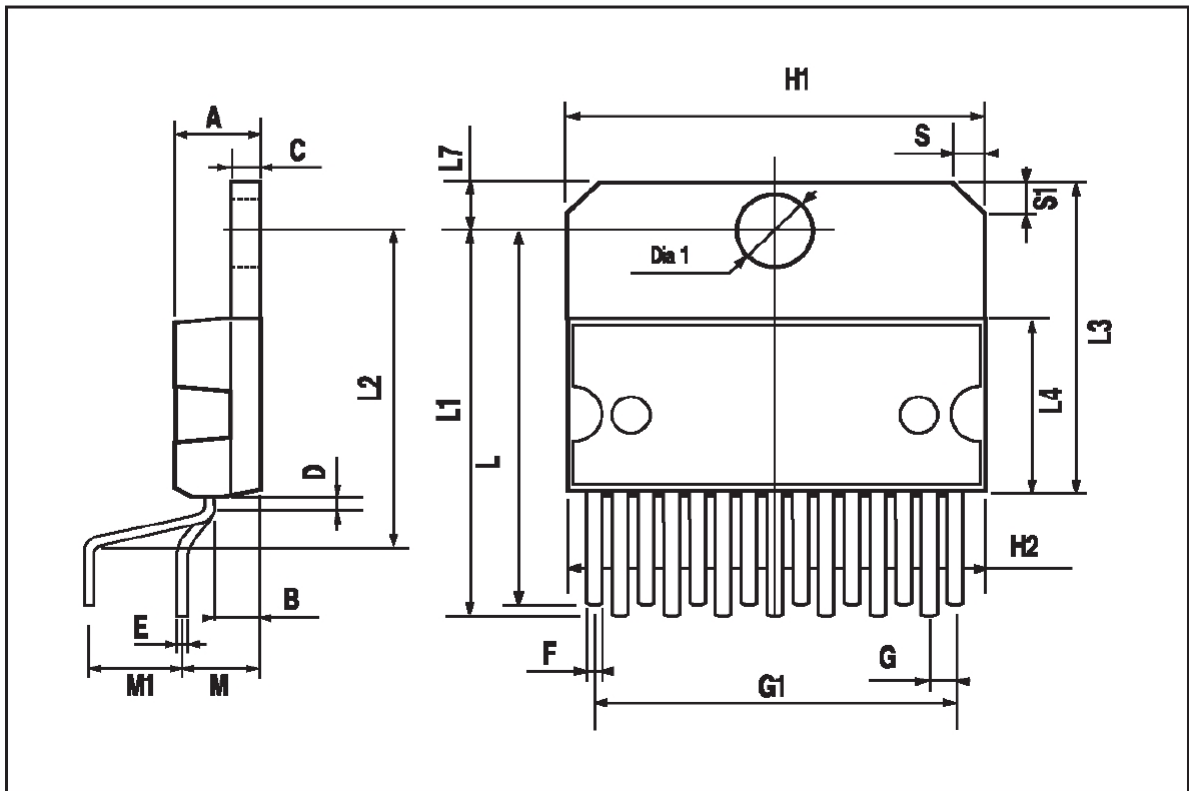
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